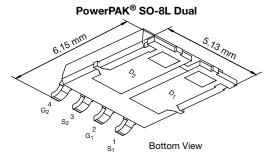
SQJ964EP



Vishay Siliconix

Automotive Dual N-Channel 60 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY		
V _{DS} (V)	60	
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.028	
I _D (A) per leg	8	
Configuration	Dual	

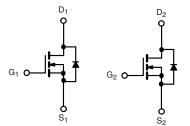


FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- AEC-Q101 Qualified^d
- 100 % R_q and UIS Tested
- Compliant to RoHS Directive 2002/95/EC



RoHS COMPLIANT HALOGEN FREE



N-Channel MOSFET N-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and Halogen-free	SQJ964EP-T1-GE3

ABSOLUTE MAXIMUM RATINGS	(T _C = 25 °C, unless	s otherwise noted	l)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current ^a	T _C = 25 °C	I	8		
	T _C = 125 °C	I _D	8		
Continuous Source Current (Diode Conduction) ^a		I _S	8	А	
Pulsed Drain Current ^b		I _{DM}	32		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	25		
Single Pulse Avalanche Energy	L = 0.1 MH	E _{AS}	31	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	D	35	W	
	T _C = 125 °C	P _D	11	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to + 175	°C	
Soldering Recommendations (Peak Temperature) ^{e, f}		-	260	-0	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	85	°C/W	
Junction-to-Case (Drain)		R _{thJC}	4.2	C/VV	

Notes

a. Package limited.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %. c. When mounted on 1" square PCB (FR-4 material).

d. Parametric verification ongoing.

e. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SO-8L. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

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SPECIFICATIONS ($T_C = 25 \text{ °C}$, PARAMETER	SYMBOL	-	MIN.	TYP.	MAX.	UNIT	
Static	STWDOL		T CONDITIONS	IVIIIA.		WIAA.	
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0, I _D = - 250 µA		60	_	_	
Gate-Source Threshold Voltage	V _{GS(th)}	üü	$V_{BS} = V_{GS}, I_D = -250 \ \mu A$		3.8	4.5	V
Gate-Source Leakage	I _{GSS}		$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	± 100	nA
Zero Gate Voltage Drain Current	IGSS	V _{GS} = 0 V			_	1	
	I _{DSS}	$V_{GS} = 0 V$ $V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 125 °C	-	_	50	μA
	.000	$V_{GS} = 0 V$	$V_{DS} = 60 \text{ V}, \text{ T}_{J} = 175 \text{ °C}$	-	-	150	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	30	-	-	А
Drain-Source On-State Resistance ^a		V _{GS} = 10 V	I _D = 9.6 A	-	0.020	0.028	Ω
	R _{DS(on)}	V _{GS} = 10 V	I _D = 9.6 A, T _J = 125 °C	-	0.033	0.046	
		V _{GS} = 10 V	I _D = 9.6 A, T _J = 175 °C	-	0.040	0.055	
Forward Transconductanceb	9 _{fs}	V _{DS} = 15 V, I _D = 9.6 A		-	30	-	S
Dynamic ^b						•	
Input Capacitance	C _{iss}		V _{GS} = 0 V V _{DS} = 30 V, f = 1 MHz	-	2360	2900	pF
Output Capacitance	C _{oss}	$V_{GS} = 0 V$		-	155	190	
Reverse Transfer Capacitance	C _{rss}			-	73	90	
Total Gate Charge ^c	Qg		$V_{DS} = 30 \text{ V}, \text{ I}_{D} = 9.6 \text{ A}$	-	38	57	nC
Gate-Source Charge ^c	Q _{gs}	V _{GS} = 10 V		-	12.5	-	
Gate-Drain Charge ^c	Q _{gd}			-	8	-	
Gate Resistance	Rg	f = 1 MHz		1	2	3	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	17	25	
Rise Time ^c	t _r	$V_{DD} = 20 \text{ V}, \text{ R}_{\text{L}} = 20 \Omega$ $\text{I}_{\text{D}} \cong 1 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 6.0 \Omega$		-	11	16	ns
Turn-Off Delay Time ^c	t _{d(off)}			-	37	45	
Fall Time ^c	t _f			-	10	15	
Source-Drain Diode Ratings and Char	acteristics ^b						
Pulsed Current ^a	I _{SM}			-	-	32	Α
Forward Voltage	V _{SD}	$I_{\rm F} = 2.9 \rm A, V_{\rm GS} = 0$		-	0.8	1.1	V

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

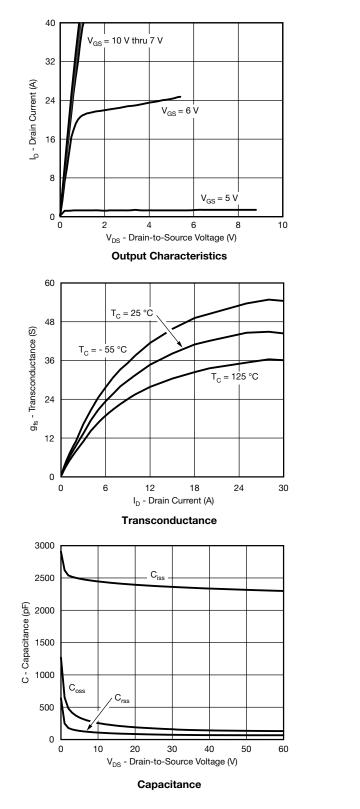
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

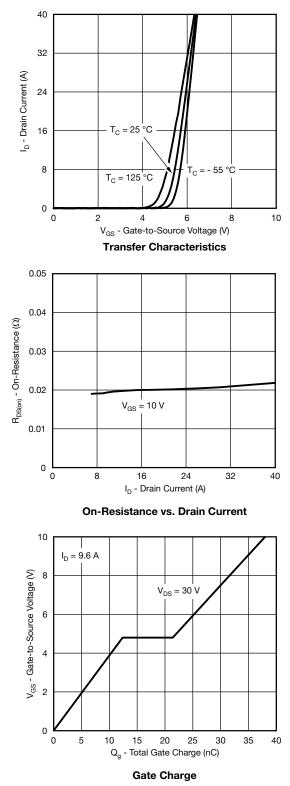
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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

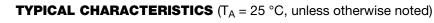




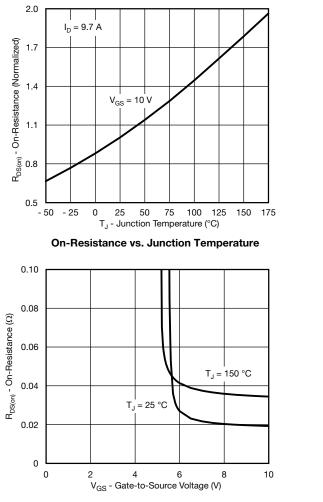
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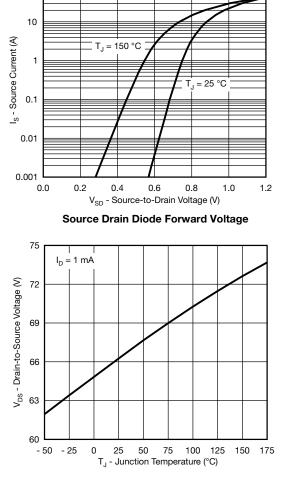
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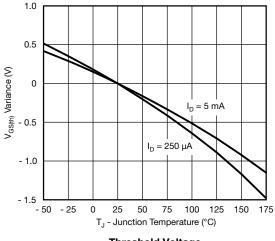


On-Resistance vs. Gate-to-Source Voltage



100

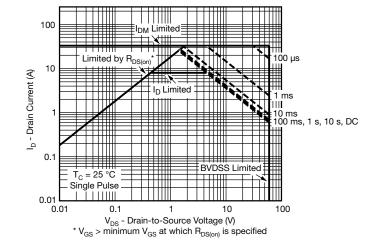
Drain-Source Breakdown vs. Junction Temperature



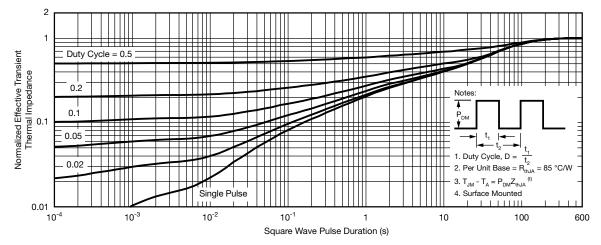


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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Safe Operating Area

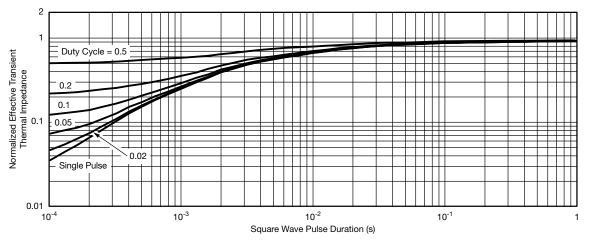


Normalized Thermal Transient Impedance, Junction-to-Ambient



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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?65167.



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